Small Signal MOSFET

-20 V, -760 mA, Single P-Channel, Gate Zener, SC-75, SC-89

Features

- Low R_{DS(on)} for Higher Efficiency and Longer Battery Life
- Small Outline Package (1.6 x 1.6 mm)
- SC-75 Standard Gullwing Package
- ESD Protected Gate
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- High Side Load Switch
- DC-DC Conversion
- Small Drive Circuits
- Battery Operated Systems such as Cell Phones, PDAs, Digital Cameras, etc.

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter	Symbol	Value	Units	
Drain-to-Source Voltage	V_{DSS}	-20	V	
Gate-to-Source Voltage	V _{GS} ±6.0		V	
Continuous Drain Current (Note 1)	I _D	-760	mA	
Power Dissipation (Note 1) SC-75 SC-89 Steady State		P _D	301 313	mW
Pulsed Drain Current	I _{DM}	±1000	mA	
Operating Junction and Storage	T _J , T _{STG}	–55 to 150	°C	
Continuous Source Current (Bo	I _S	-250	mA	
Lead Temperature for Soldering (1/8 in from case for 10 s)	T _L	260	°C	
Gate-to-Source ESD Rating - (Human Body Model	ESD	1800	V	

THERMAL RESISTANCE RATINGS

Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$		°C/W
SC-75		415	
SC-89		400	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).

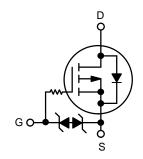


ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
	0.26 Ω @ -4.5 V	
–20 V	0.35 Ω @ -2.5 V	–760 mA
	0.49 Ω @ -1.8 V	

P-Channel MOSFET

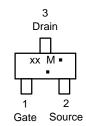


MARKING DIAGRAM & PIN ASSIGNMENT





SC-89 CASE 463C



xx = Device Code M = Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise stated)

Parameter	Symbol Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS					I		
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V, } I_{D} = -250 \mu\text{A}$				V	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 \text{ V}, V_{DS} = -16 \text{ V}$		-1.0	-100	nA	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		±1.0	±10	μΑ	
ON CHARACTERISTICS (Note 2)			•	•	•	•	
Gate Threshold Voltage	V _{GS(TH)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-0.45		-1.2	V	
Drain-to-Source On Resistance	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -350 \text{ mA}$		0.26	0.36	Ω	
		$V_{GS} = -2.5 \text{ V}, I_D = -300 \text{ mA}$		0.35	0.45		
		$V_{GS} = -1.8 \text{ V}, I_D = -150 \text{ mA}$		0.49	1.0		
Forward Transconductance	9FS	$V_{DS} = -10 \text{ V}, I_D = -250 \text{ mA}$		0.4		S	
CHARGES AND CAPACITANCES			•	•			
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 1.0 \text{ MHz,}$ $V_{DS} = -5.0 \text{ V}$		156		pF	
Output Capacitance	C _{OSS}	$V_{DS} = -5.0 \text{ V}$		28			
Reverse Transfer Capacitance	C _{RSS}			18			
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = -4.5 \text{ V}, V_{DD} = -10 \text{ V},$		2.1		nC	
Threshold Gate Charge	Q _{G(TH)}	$I_D = -0.3 \text{ A}$		0.125		1	
Gate-to-Source Charge	Q_{GS}			0.325			
Gate-to-Drain Charge	Q_{GD}			0.5		7	
SWITCHING CHARACTERISTICS (Note	3)		•	•	•		
Turn-On Delay Time	td _(ON)	$V_{GS} = -4.5 \text{ V}, V_{DD} = -10 \text{ V},$		8.0		ns	
Rise Time	t _r	I_D = -200 mA, R_G = 10 Ω		8.2			
Turn-Off Delay Time	td _(OFF)			29			
Fall Time	t _f			20.4			
DRAIN-SOURCE DIODE CHARACTERI	STICS			-		-	
Forward Diode Voltage	V_{SD}	$V_{GS} = 0 \text{ V, } I_{S} = -250 \text{ mA}$		-0.72	-1.1	V	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

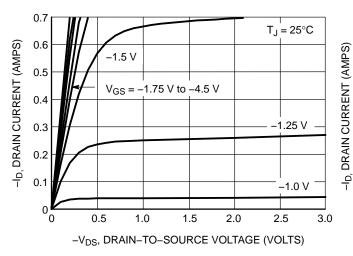
Device	Marking	Package	Shipping [†]
NTA4151PT1G	TN	SC-75 (Pb-Free)	3000 / Tape & Reel
NTE4151PT1G	ТМ	SC-89 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{2.} Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.

^{3.} Switching characteristics are independent of operating junction temperatures.

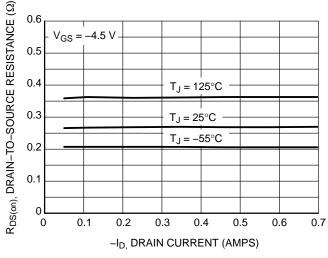
TYPICAL ELECTRICAL CHARACTERISTICS



0.6 $V_{DS} \ge -10 \text{ V}$ 0.5 0.4 0.3 0.2 T_J = 125°C $T_J = 25^{\circ}C$ 0.1 $T_J = -55^{\circ}C$ 0 L 0.4 8.0 1.2 1.6 2.0 -V_{GS}, GATE-TO-SOURCE VOLTAGE (VOLTS)

Figure 1. On-Region Characteristics

Figure 2. Transfer Characteristics



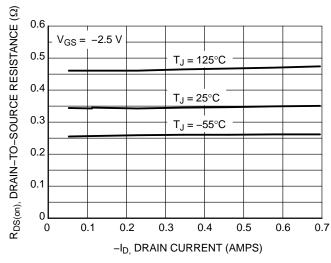
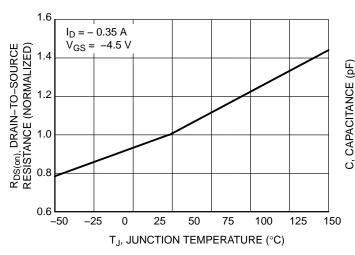


Figure 3. On–Resistance vs. Drain Current and Temperature

Figure 4. On–Resistance vs. Drain Current and Temperature



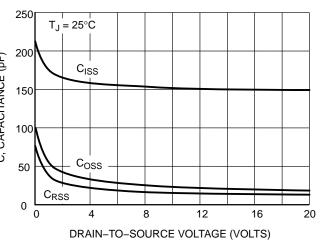
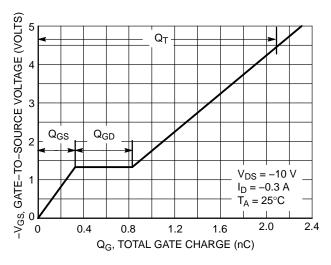


Figure 5. On–Resistance Variation with Temperature

Figure 6. Capacitance Variation

TYPICAL ELECTRICAL CHARACTERISTICS



0.7 $V_{GS} = 0 V$ 0.6 0.6 0.5 0.4 0.3 0.2 0.2 0.2 0.2 0.3 0.2 0.3 0.2 0.3 0.4 0.3 0.5 0.4 0.5 0

Figure 7. Gate-to-Source Voltage vs. Total Gate Charge

Figure 8. Diode Forward Voltage vs. Current

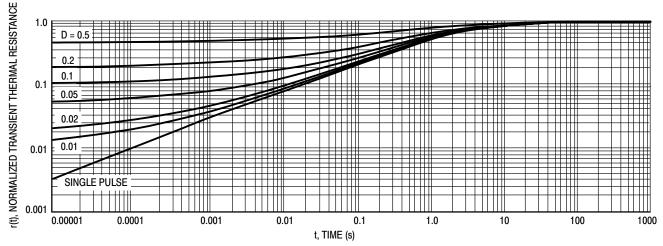
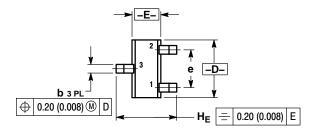


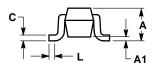
Figure 9. Normalized Thermal Response

PACKAGE DIMENSIONS

SC-75/SOT-416

CASE 463 ISSUE F



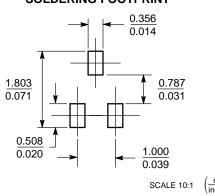


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
E	0.70	0.80	0.90	0.027	0.031	0.035
е	1	.00 BSC)		0.04 BSC	
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

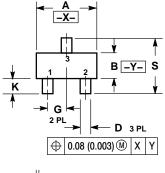
SOLDERING FOOTPRINT*

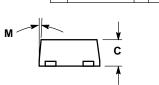


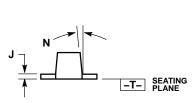
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SC-89, 3-LEAD CASE 463C-03 **ISSUE C**





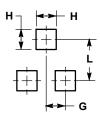


NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
 THICKNESS OF BASE MATERIAL.
- 463C-01 OBSOLETE, NEW STANDARD 463C-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.60	1.70	0.059	0.063	0.067
В	0.75	0.85	0.95	0.030	0.034	0.040
С	0.60	0.70	0.80	0.024	0.028	0.031
D	0.23	0.28	0.33	0.009	0.011	0.013
G	0	.50 BS0)	0.020 BSC		
Н	0.53 REF			0.021 REF		
J	0.10	0.15	0.20	0.004	0.006	0.008
K	0.30	0.40	0.50	0.012	0.016	0.020
L	1.10 REF			0.043 REF		
M			10			10
N		-	10			10
S	1.50	1.60	1.70	0.059	0.063	0.067

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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